

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China









Is Now Part of



ON Semiconductor®

To learn more about ON Semiconductor, please visit our website at www.onsemi.com

ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any EDA Class 3 medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, emplo



June 2013

FJP5555

NPN Silicon Transistor

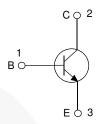
Features

- · Fast Speed Switching
- · Wide Safe Operating Area
- · High Voltage Capability

Application

- Electronic Ballast
- · Switch Mode Power Supplies





Ordering Information

Part Number	Marking	Package	Packing Method
FJP5555TU	J5555	TO-220	Rail

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_A = 25^{\circ}$ C unless otherwise noted.

Symbol	Parameter	Value	Units
BV _{CBO}	Collector-Base Voltage	1050	V
BV _{CEO}	Collector-Emitter Voltage	400	V
BV _{EBO}	Emitter-Base Voltage	14	V
I _C	Collector Current (DC)	5	Α
I _{CP}	Collector Current (Pulse)	10	Α
I _B	Base Current (DC)	2	Α
I _{BP}	Base Current (Pulse)	4	Α
TJ	Junction Temperature	150	°C
T _{STG}	Storage Temperature	- 55 to +150	°C

Thermal Characteristics

Values are at $T_A = 25^{\circ}$ C unless otherwise noted

Symbol	Parameter		Value	Units
P _D Tota	Total Device Dissipation	$T_A = 25^{\circ}C$	1.38	W
		$T_C = 25^{\circ}C$	75	W
$R_{\theta ja}^{(1)}$	Thermal Resistance, Junction to Ambient		90	°C/W
$R_{\theta jc}^{(2)}$	Thermal Resistance, Junction to Case		1.66	°C/W

1

Notes

- 1. $R_{\theta ja}$ test board and fixture under natural convection, JESD51-10 recommended thermal test board.
- 2. $R_{\theta ic}$ test fixture under infinite cooling condition.

Electrical Characteristics(3)

Values are at $T_A = 25$ °C unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Voltage	$I_C = 500 \mu A, I_E = 0$	1050			V
BV _{CEO}	Collector-Emitter Voltage	$I_C = 5 \text{ mA}, I_B = 0$	400			V
BV _{EBO}	Emitter-Base Voltage	$I_E = 500 \mu A, I_C = 0$	14			V
h _{FE}	DC Comment Calin	$V_{CE} = 5 \text{ V}, I_{C} = 10 \text{ mA}$	10			
	DC Current Gain	$V_{CE} = 3 \text{ V}, I_{C} = 0.8 \text{ A}$	20		40	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	$I_C = 1 A, I_B = 0.2 A$			0.5	V
		$I_C = 3.5 \text{ A}, I_B = 1.0 \text{ A}$			1.5	V
V _{BE} (sat)	Base-Emitter Saturation Voltage	$I_C = 3.5 \text{ A}, I_B = 1.0 \text{ A}$			1.2	V
C _{ob}	Output Capacitance	V _{CB} = 10 V, f = 1 MHz		45		pF
t _{ON}	Turn-On Time	$V_{CC} = 125 \text{ V}, I_{C} = 0.5 \text{ A},$ $I_{B1} = 45 \text{ mA}, I_{B2} = 0.5 \text{ A},$ $R_{L} = 250 \Omega$			1.0	μs
t _{STG}	Storage Time				1.2	μs
t _F	Fall Time				0.3	μs
t _{ON}	Turn-On Time	$V_{CC} = 250 \text{ V}, I_{C} = 2.5 \text{ A},$ $I_{B1} = 0.5 \text{ A}, I_{B2} = 1.0 \text{ A},$ $R_{L} = 100 \Omega$			2.0	μs
t _{STG}	Storage Time				2.5	μs
t _F	Fall Time				0.3	μs
EAS	Avalanche Energy	L = 2 mH	6			mJ

Note:

3. Pulse test: pulse width $\leq 300~\mu s,$ duty cycle $\leq 2\%.$

Typical Performance Characteristics

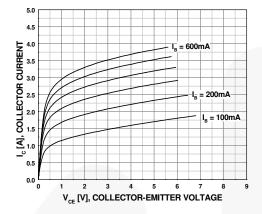


Figure 1. Static Characteristics

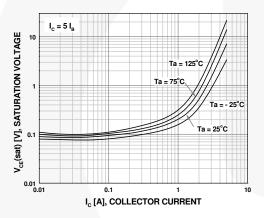


Figure 3. Saturation Voltage

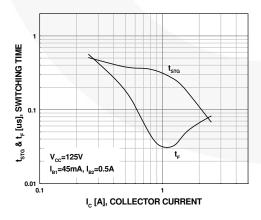


Figure 5. Resistive Load Switching

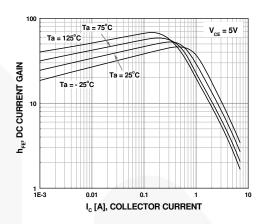


Figure 2. DC Current Gain

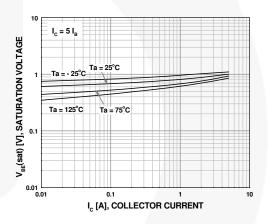


Figure 4. Saturation Voltage

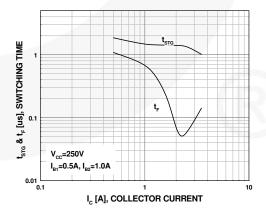


Figure 6. Resistive Load Switching

Typical Performance Characteristics (Continued)

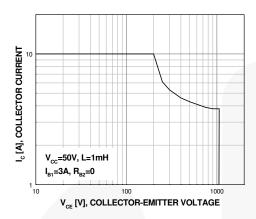


Figure 7. Reverse Biased Safe Operating Area

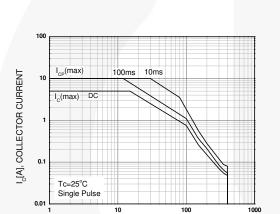


Figure 9. Forward Biased Safe Operating Area

 $V_{_{\mathrm{CF}}}[V]$, COLLECTOR-EMITTER VOLTAGE

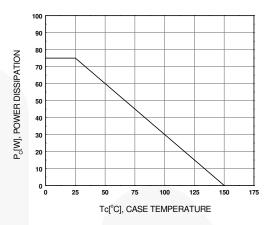
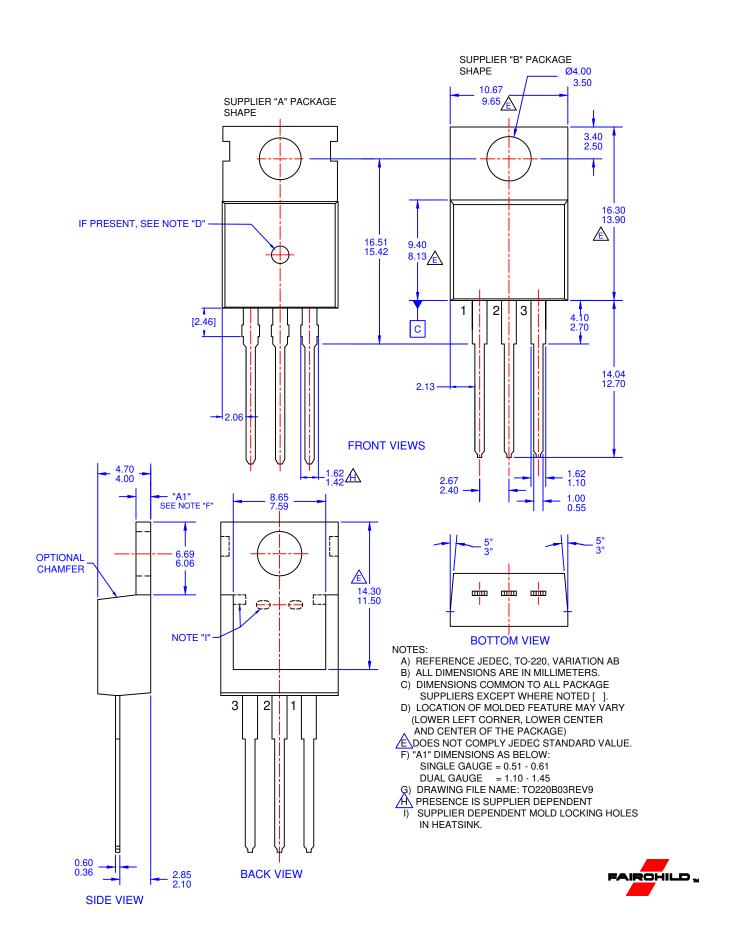


Figure 8. Power Derating



ON Semiconductor and in are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and exp

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada
Europe, Middle East and Africa Technical Support:
Phone: 421 33 790 2910

Phone: 421 33 790 2910

Japan Customer Focus Center

Phone: 81–3–5817–1050

ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative